

PTO-1449 REPRODUCED			ATTORNEY DOCKET NO. 1866.2005-000	APPLICATION NO. 10/037,461
INFORMATION DISCLOSURE SITUATION IN AN APPLICATION			APPLICANT Richard Sahara et al.	
May 20, 2002 MAY 23 2002 PATENT & TRADEMARK OFFICE			FILING DATE November 9, 2001	GROUP 2881

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE IF APPROPRIATE
dw	AA	4,719,636	1/12/88	Yamaguchi	372	50	
	AB	6,028,881	2/22/00	Ackerman et al.	372	75	
	AC	6,108,469	8/22/00	Chen	385	24	
	AD	6,122,299	9/19/00	DeMars et al.	372	20	
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION YES NO
	AL						
	AM						
	AN						
	AO						
	AP						
	AQ						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

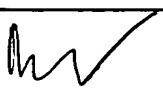
dw	AR	Kazmierski, Christophe, et al., "1.5 μ m DFB Lasers with New Current-Induced Gain Gratings," <i>IEEE Journal of Selected Topics in Quantum Elec.</i> , 1(2): 371-374 (1995).
dw	AS	Nakano, Yoshiaki, et al., "Reduction of Excess Intensity Noise Induced by External Reflection in a Gain-Coupled Distributed Feedback Semiconductor Laser," <i>IEEE Journal of Quantum Electronics</i> , 27(6): 1732-1735 (1991).
dw	AT	Huang, Yidong, et al., "Isolator-Free 2.5 Gb/s 80-km Transmission by Directly Modulated $\lambda/8$ Phase-Shifted DFB-LDs Under Negative Feedback Effect of Mirror Loss," <i>IEEE Photonics Technology Letters</i> , 13(3): 245-247 (2001).

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DATE CONSIDERED

10/06/03

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DU	AU	Thedrez, B., et al., "1.3μm tapered DFB lasers for isolator-free 2.5 Gbits all-optical networks," OPTO+, Groupement d'Intérêt Economique, Alcatel Corporate Research Center, Marcoussis, France.					
	AV	Xing-sha, Zhou and Peida, Ye, "Intensity Noise of Semiconductor Laser In Presence Of Arbitrary Optical Feedback," <i>Electronics Letters</i> , 25(7): 446-447 (1989).					
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	AX	Favre, F., "Sensitivity to External Feedback For Gain-Coupled DFB Semiconductor Lasers," <i>Electronics Letters</i> , 27(5): 433-435 (1991).					
	AY	Nakano, Y., et al., "Resistance to External Optical Feedback in a Gain-Coupled Semiconductor DFB Laser," University of Tokyo, Bunkyo-ku, Tokyo 113, Japan.					
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